
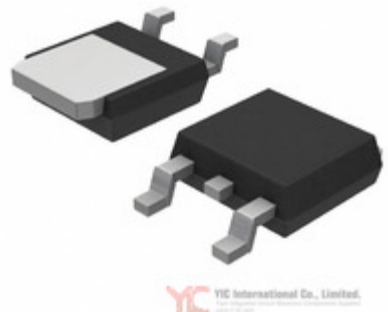


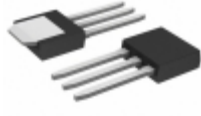
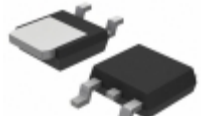
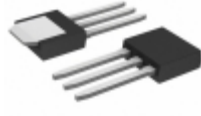

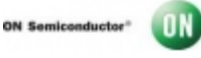
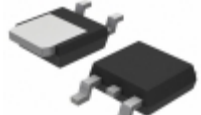
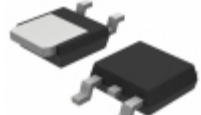
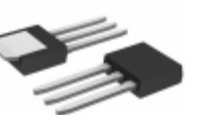
	<h2 style="color: red;">NTD32N06LT4G</h2>
	<p>Hersteller-Teilenummer: NTD32N06LT4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 32A DPAK</p> <p>Datenblätter:  NTD32N06LT4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10529 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD32N06LT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 32A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	10529 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.5W (Ta), 93.75W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Ta)
Rds On (Max) @ Id, Vgs	28 mOhm @ 16A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1700pF @ 25V
Verpackung	Tape & Reel (TR)












































NTD32N06LT4G ist neu im Original, Suche NTD32N06LT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD32N06LT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD32N06LT4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD3808N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>	 <p>NTD32N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06L-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD3808N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>
 <p>NTD32N06LT4 AMI Semiconductor / ON Semiconductor NTD32N06LT4 ON/</p>	 <p>NTD32N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD3813N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 9.6A IPAK</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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